

DATA SHEET

74LV125

Quad buffer/line driver (3-State)

Product specification
Supersedes data of 1997 Feb 03
IC24 Data Handbook

1998 Apr 28

Quad buffer/line driver (3-State)

74LV125

FEATURES

- Wide operating voltage: 1.0 to 5.5 V
- Optimized for Low Voltage applications: 1.0 to 3.6 V
- Accepts TTL input levels between $V_{CC} = 2.7$ V and $V_{CC} = 3.6$ V
- Typical V_{OLP} (output ground bounce) < 0.8 V at $V_{CC} = 3.3$ V, $T_{amb} = 25^{\circ}\text{C}$.
- Typical V_{OHV} (output V_{OH} undershoot) > 2 V at $V_{CC} = 3.3$ V, $T_{amb} = 25^{\circ}\text{C}$.
- Output capability: bus driver
- I_{CC} category: MSI

DESCRIPTION

The 74LV125 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT125.

The 74LV125 consists of four non-inverting buffers/line drivers with 3-state outputs. The 3-state outputs (nY) are controlled by the output enable input (nOE). A HIGH at nOE causes the outputs to assume a high impedance OFF-state.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}\text{C}$; $t_r = t_f \leq 2.5$ ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PHL}/t_{PLH}	Propagation delay nA to nY	$C_L = 15$ pF; $V_{CC} = 3.3$ V	9	ns
C_I	Input capacitance		3.5	pF
C_{PD}	Power dissipation capacitance per buffer	$V_{CC} = 3.3$ V; $V_I = \text{GND to } V_{CC}^1$	22	pF

NOTE:

- C_{PD} is used to determine the dynamic power dissipation (P_D in μW)
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz; C_L = output load capacitance in pF;
 f_o = output frequency in MHz; V_{CC} = supply voltage in V;
 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
14-Pin Plastic DIL	-40°C to $+125^{\circ}\text{C}$	74LV125 N	74LV125 N	SOT27-1
14-Pin Plastic SO	-40°C to $+125^{\circ}\text{C}$	74LV125 D	74LV125 D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to $+125^{\circ}\text{C}$	74LV125 DB	74LV125 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to $+125^{\circ}\text{C}$	74LV125 PW	74LV125PW DH	SOT402-1

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 4, 10, 13	1OE – 4OE	Data enable inputs (active LOW)
2, 5, 9, 12	1A – 4A	Data inputs
3, 6, 8, 11	1Y – 4Y	Data Outputs
7	GND	Ground (0 V)
14	V_{CC}	Positive supply voltage

FUNCTION TABLE

INPUTS		OUTPUT
nOE	nA	nY
L	L	L
L	H	H
H	X	Z

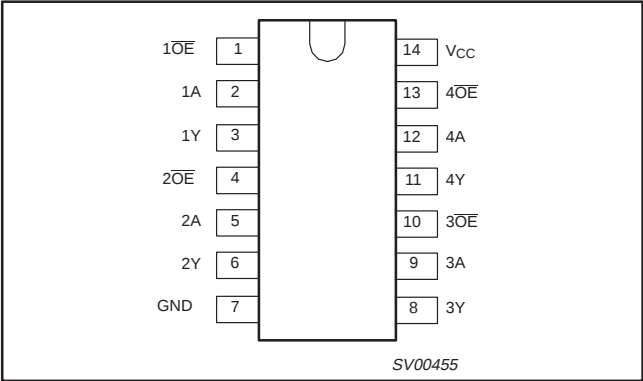
NOTES:

H = HIGH voltage level
 L = LOW voltage level
 X = don't care
 Z = high impedance OFF-state

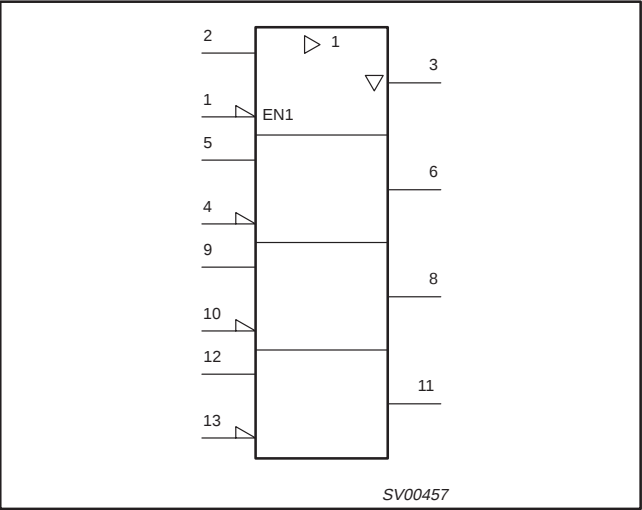
Quad buffer/line driver (3-State)

74LV125

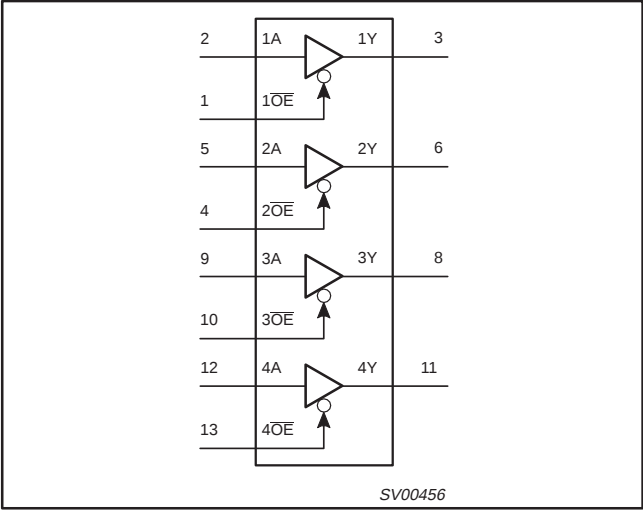
PIN CONFIGURATION



LOGIC SYMBOL (IEEE/IEC)



LOGIC SYMBOL



RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1	1.0	3.3	5.5	V
V _I	Input voltage		0	–	V _{CC}	V
V _O	Output voltage		0	–	V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	–40 –40		+85 +125	°C
t _r , t _f	Input rise and fall times	V _{CC} = 1.0V to 2.0V V _{CC} = 2.0V to 2.7V V _{CC} = 2.7V to 3.6V V _{CC} = 3.6V to 5.5V	– – – –	– – – –	500 200 100 50	ns/V

NOTE:

1. The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 5.5V.

Quad buffer/line driver (3-State)

74LV125

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134).

Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		-0.5 to +7.0	V
$\pm I_{IK}$	DC input diode current	$V_I < -0.5$ or $V_I > V_{CC} + 0.5V$	20	mA
$\pm I_{OK}$	DC output diode current	$V_O < -0.5$ or $V_O > V_{CC} + 0.5V$	50	mA
$\pm I_O$	DC output source or sink current – bus driver outputs	$-0.5V < V_O < V_{CC} + 0.5V$	35	mA
$\pm I_{GND}$, $\pm I_{CC}$	DC V_{CC} or GND current for types with – bus driver outputs		70	mA
T_{stg}	Storage temperature range		-65 to +150	°C
P_{TOT}	Power dissipation per package – plastic DIL – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS					UNIT
			-40°C to +85°C			-40°C to +125°C		
			MIN	TYP ¹	MAX	MIN	MAX	
V _{IH}	HIGH level Input voltage	V _{CC} = 1.2 V	0.9			0.9		V
		V _{CC} = 2.0 V	1.4			1.4		
		V _{CC} = 2.7 to 3.6 V	2.0			2.0		
		V _{CC} = 4.5 to 5.5 V	0.7 * V _{CC}			0.7 * V _{CC}		
V _{IL}	LOW level Input voltage	V _{CC} = 1.2 V			0.3		0.3	V
		V _{CC} = 2.0 V			0.6		0.6	
		V _{CC} = 2.7 to 3.6 V			0.8		0.8	
		V _{CC} = 4.5 to 5.5			0.3 * V _{CC}		0.3 * V _{CC}	
V _{OH}	HIGH level output voltage; all outputs	V _{CC} = 1.2 V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA		1.2				V
		V _{CC} = 2.0 V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA	1.8	2.0		1.8		
		V _{CC} = 2.7 V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA	2.5	2.7		2.5		
		V _{CC} = 3.0 V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA	2.8	3.0		2.8		
		V _{CC} = 4.5 V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA	4.3	4.5		4.3		
V _{OH}	HIGH level output voltage; BUS driver outputs	V _{CC} = 3.0 V; V _I = V _{IH} or V _{IL} ; -I _O = 8mA	2.40	2.82		2.20		V
		V _{CC} = 4.5 V; V _I = V _{IH} or V _{IL} ; -I _O = 16mA	3.60	4.20		3.50		
V _{OL}	LOW level output voltage; all outputs	V _{CC} = 1.2 V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0				V
		V _{CC} = 2.0 V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0	0.2		0.2	
		V _{CC} = 2.7 V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0	0.2		0.2	
		V _{CC} = 3.0 V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0	0.2		0.2	
		V _{CC} = 4.5 V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0	0.2		0.2	
V _{OL}	LOW level output voltage; BUS driver outputs	V _{CC} = 3.0 V; V _I = V _{IH} or V _{IL} ; I _O = 8mA		0.20	0.40		0.50	V
		V _{CC} = 4.5 V; V _I = V _{IH} or V _{IL} ; I _O = 16mA		0.35	0.55		0.65	

Quad buffer/line driver (3-State)

74LV125

DC ELECTRICAL CHARACTERISTICS (Continued)

Over recommended operating conditions, voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS					UNIT
			-40°C to +85°C			-40°C to +125°C		
			MIN	TYP ¹	MAX	MIN	MAX	
I _I	Input leakage current	V _{CC} = 5.5 V; V _I = V _{CC} or GND			1.0		1.0	μA
I _{OZ}	3-State output OFF-state current	V _{CC} = 5.5 V; V _I = V _{IH} or V _{IL} ; V _O = V _{CC} or GND			5		10	μA
I _{CC}	Quiescent supply current; MSI	V _{CC} = 5.5 V; V _I = V _{CC} or GND; I _O = 0			20.0		160	μA
ΔI _{CC}	Additional quiescent supply current per input	V _{CC} = 2.7 V to 3.6 V; V _I = V _{CC} – 0.6 V			500		850	μA

NOTE:1. All typical values are measured at $T_{amb} = 25^\circ\text{C}$.**AC CHARACTERISTICS**GND = 0V; $t_r = t_f \leq 2.5\text{ns}$; $C_L = 50\text{pF}$; $R_L = 1\text{k}\Omega$

SYMBOL	PARAMETER	WAVEFORM	CONDITION	LIMITS					UNIT
				−40 to +85 °C			−40 to +125 °C		
			V _{CC} (V)	MIN	TYP ¹	MAX	MIN	MAX	
t _{PHL} /t _{PLH}	Propagation delay nA to nY	Figures 1, 2	1.2		55				ns
			2.0		19	24		31	
			2.7		14	18		23	
			3.0 to 3.6		10 ²	14		18	
			4.5 to 5.5			12		15	
t _{PZH} /t _{PZL}	3-State output enable time nOE to nY	Figures 2, 3	1.2		75				ns
			2.0		26	31		39	
			2.7		19	23		29	
			3.0 to 3.6		14 ²	18		23	
			4.5 to 5.5			15		19	
t _{PHZ} /t _{PLZ}	3-State output disable time nOE to nY	Figures 2, 3	1.2		65				ns
			2.0		24	32		39	
			2.7		18	24		29	
			3.0 to 3.6		14 ²	20		24	
			4.5 to 5.5			17		21	

NOTES:1. Unless otherwise stated, all typical values are measured at $T_{amb} = 25^\circ\text{C}$ 2. Typical values are measured at $V_{CC} = 3.3 \text{ V}$.

Quad buffer/line driver (3-State)

74LV125

AC WAVEFORMS

$V_M = 1.5\text{ V}$ at $V_{CC} \geq 2.7\text{ V}$ and $\leq 3.6\text{ V}$;
 $V_M = 0.5 \times V_{CC}$ at $V_{CC} < 2.7\text{ V}$ and $\geq 4.5\text{ V}$.
 V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.
 $V_X = V_{OL} + 0.3\text{ V}$ at $V_{CC} \geq 2.7\text{ V}$ and $\leq 3.6\text{ V}$;
 $V_X = V_{OL} + 0.1 \times V_{CC}$ at $V_{CC} < 2.7\text{ V}$ and $\geq 4.5\text{ V}$.
 $V_Y = V_{OH} - 0.3\text{ V}$ at $V_{CC} \geq 2.7\text{ V}$ and $\leq 3.6\text{ V}$;
 $V_Y = V_{OH} - 0.1 \times V_{CC}$ at $V_{CC} < 2.7\text{ V}$ and $\geq 4.5\text{ V}$.

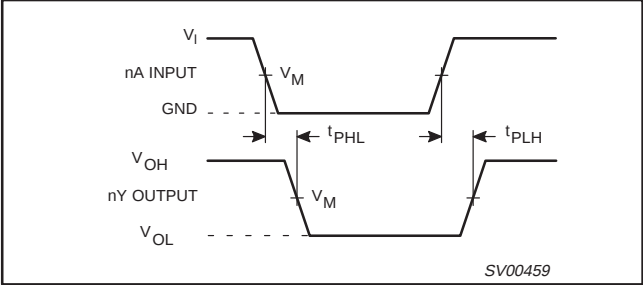


Figure 1. Input (nA) to output (nY) propagation delays and output transition times.

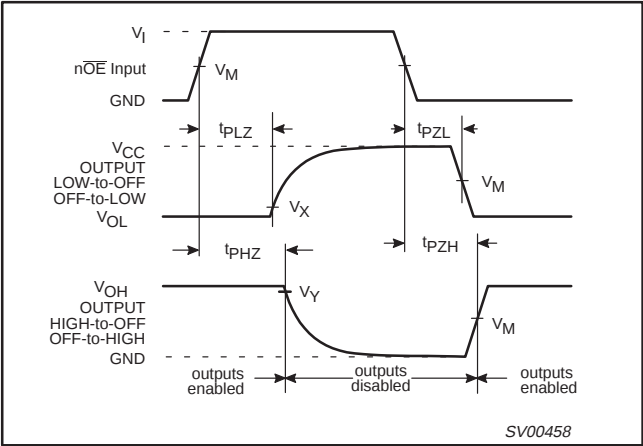
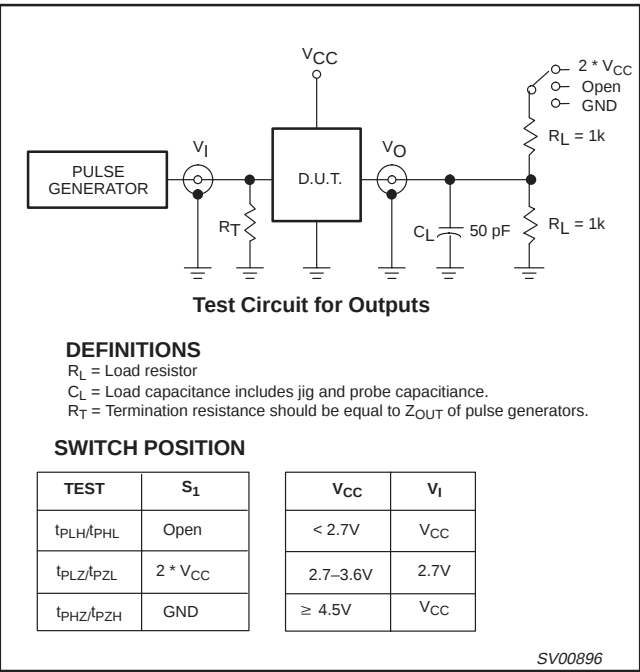


Figure 2. 3-state enable and disable times.

TEST CIRCUIT



DEFINITIONS
 R_L = Load resistor
 C_L = Load capacitance includes jig and probe capacitance.
 R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

SWITCH POSITION

TEST	S_1	V_{CC}	V_I
t_{PLH}/t_{PHL}	Open	$< 2.7\text{ V}$	V_{CC}
t_{PLZ}/t_{PZL}	$2 \times V_{CC}$	$2.7\text{--}3.6\text{ V}$	2.7 V
t_{PHZ}/t_{PZH}	GND	$\geq 4.5\text{ V}$	V_{CC}

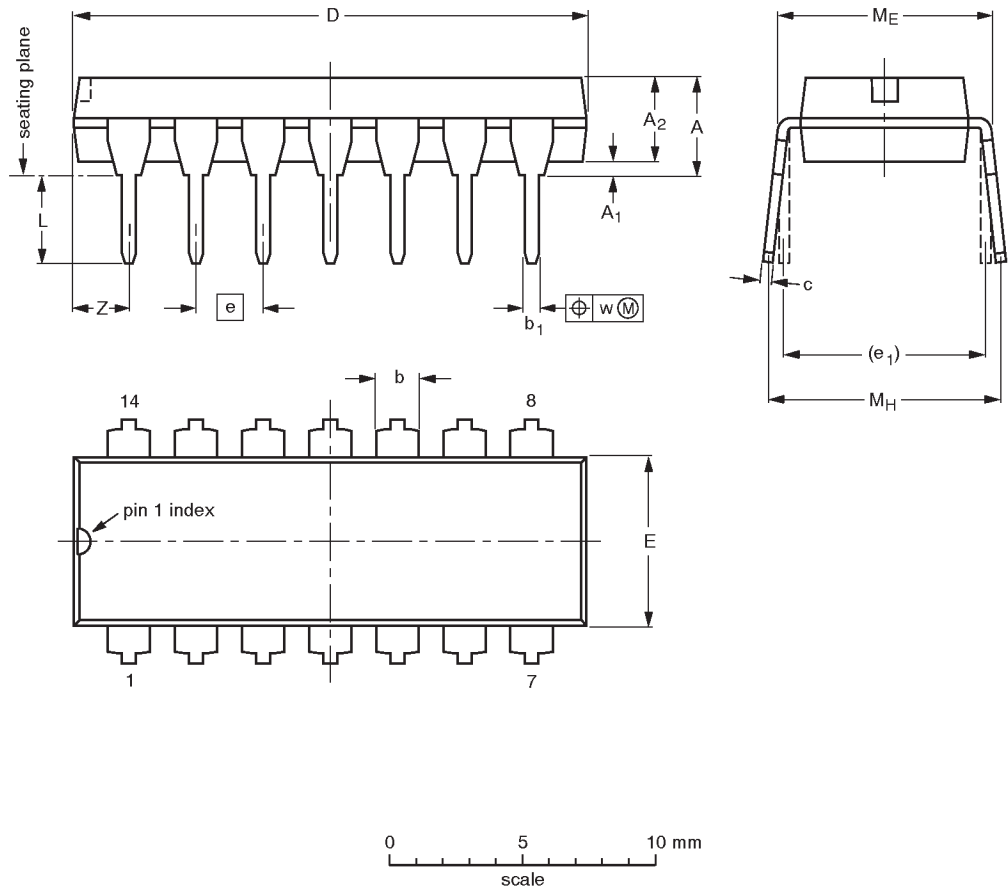
Figure 3. Load circuitry for switching times.

Quad buffer/line driver (3-State)

74LV125

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	c	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

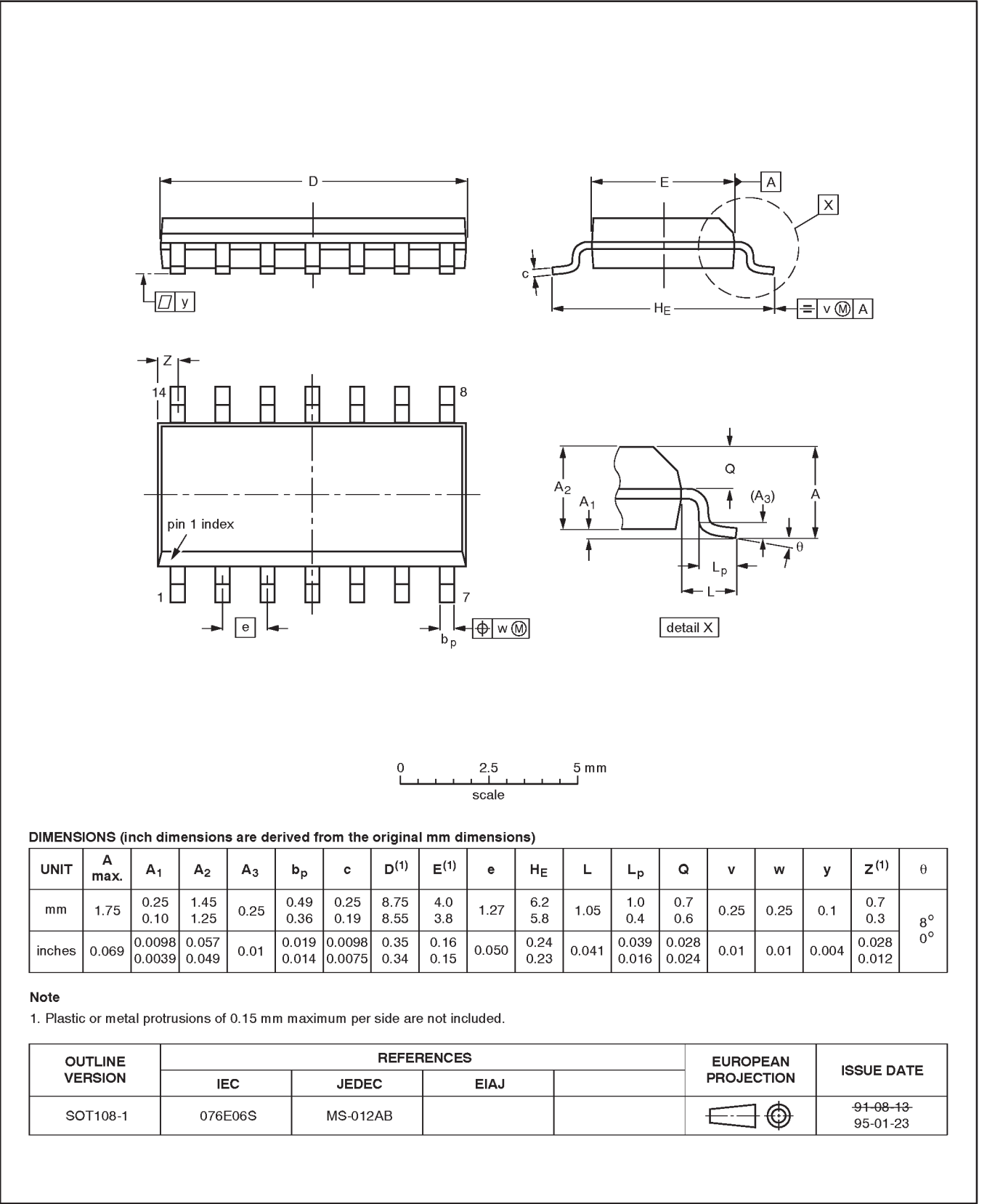
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT27-1	050G04	MO-001AA				92-11-17 95-03-11

Quad buffer/line driver (3-State)

74LV125

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1

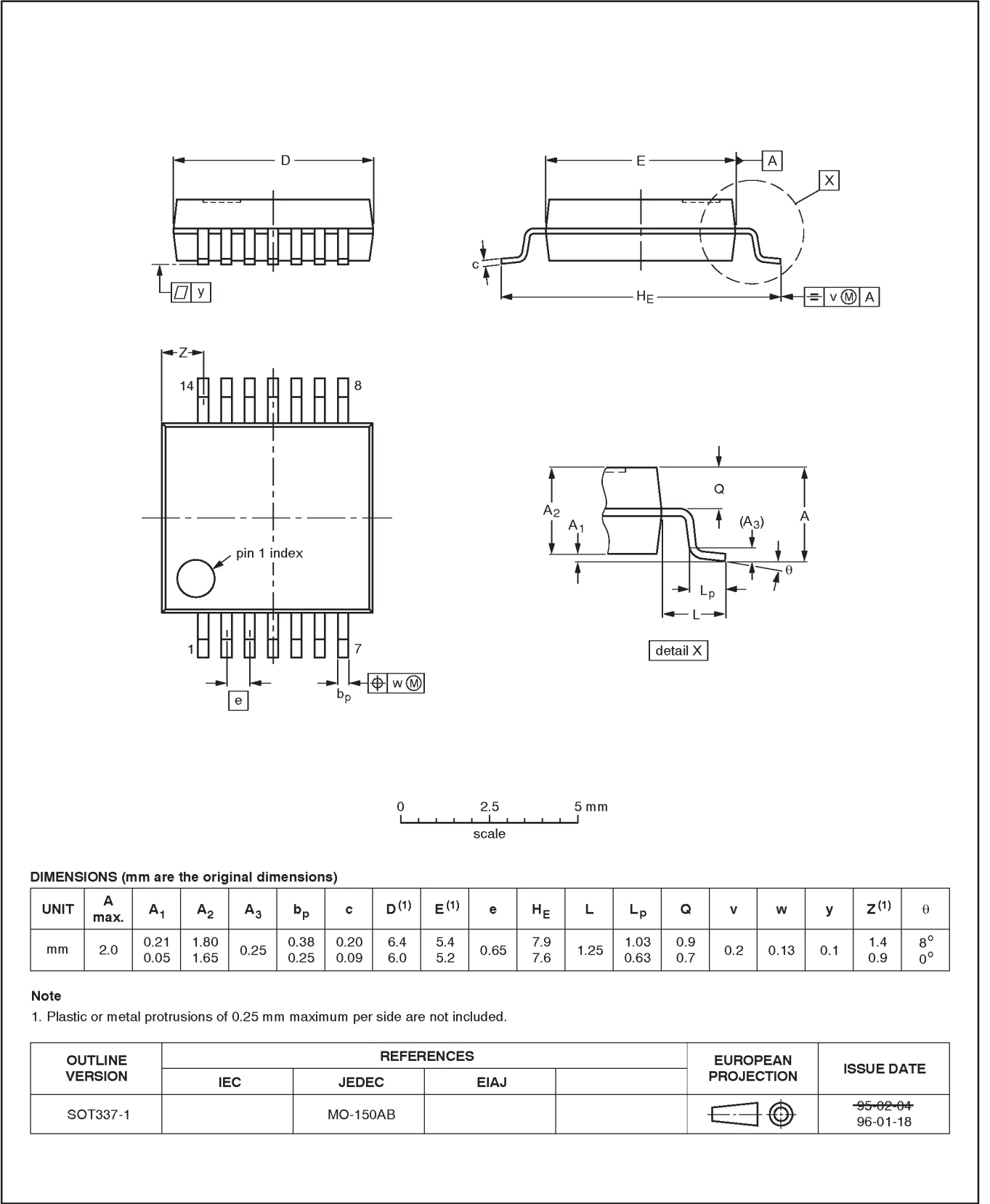


Quad buffer/line driver (3-State)

74LV125

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1

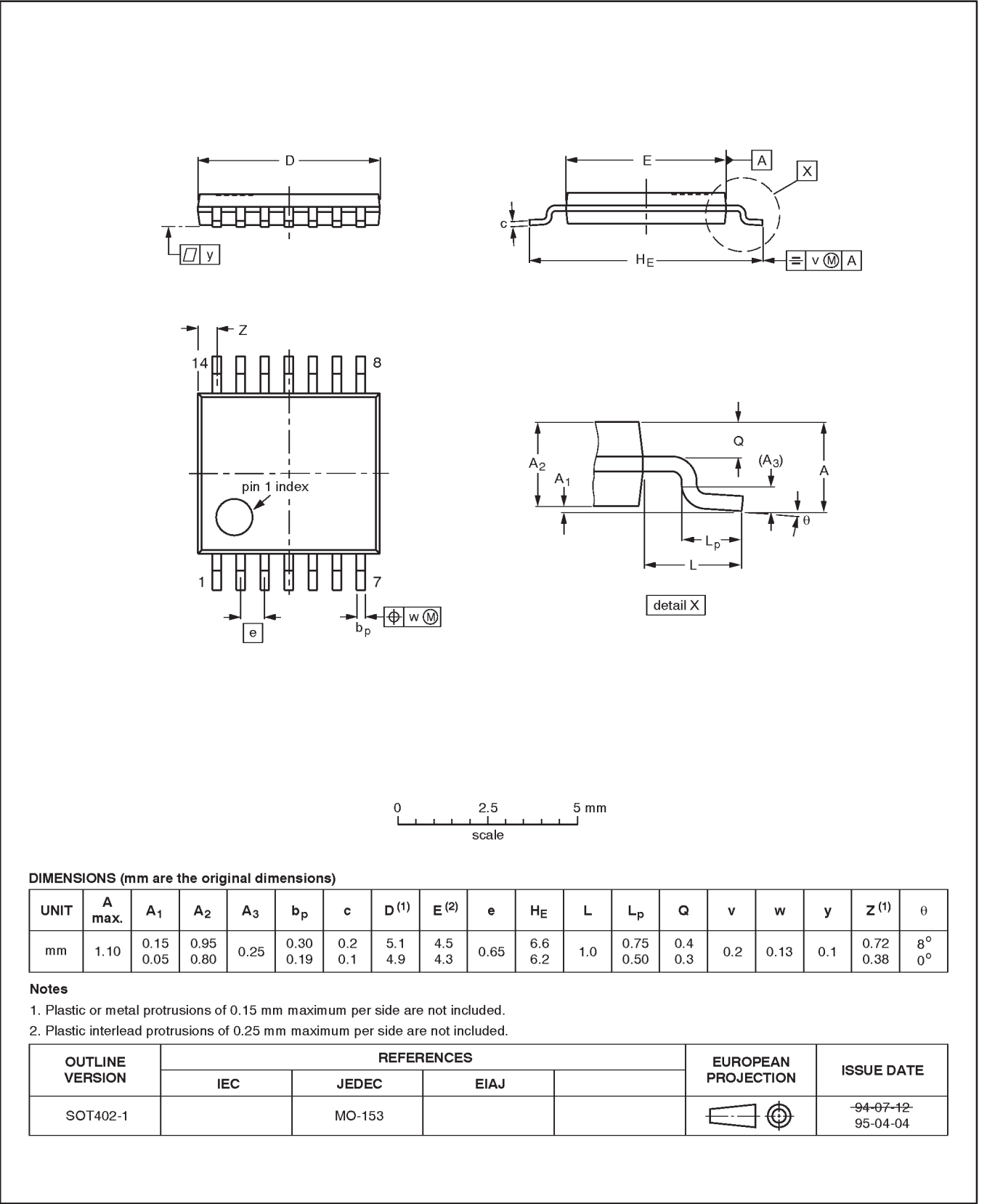


Quad buffer/line driver (3-State)

74LV125

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



Quad buffer/line driver (3-State)**74LV125**

NOTES

Quad buffer/line driver (3-State)

74LV125

DEFINITIONS		
Data Sheet Identification	Product Status	Definition
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
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